

# M16C/65 Group

# **External Buses**

REC05B0113-0100 Rev.1.00 May 20, 2010

# 1. Abstract

This document introduces the external bus.

# 2. Introduction

This application note applies to the M16C/65 Group microcomputer (MCU).

This application note can be used with other M16C Family MCUs which have the same special function registers (SFRs) as the above group. Check the manual for any modifications to functions. Careful evaluation is recommended before using the program described in this application note.

# 3. External Buses

# 3.1 Overview

Memory and I/O external expansion can be connected to the MCU easily using external buses. When memory expansion mode or microprocessor mode is selected for the processor mode, some of the pins function as the address bus, the data bus, and as control signals, which makes the external buses operational.

When accessing an external area, an 8-bit data bus width or 16-bit data bus width can be selected based on the BYTE pin level. The 16-bit width is used to access internal areas regardless of the BYTE pin level. Fix the BYTE pin either high or low. 8-bit and 16-bit data bus widths cannot be used together in an external area.

#### 3.2 Data Access

# 3.2.1 Data Bus Width

When the voltage level input to the BYTE pin is high, the external data bus width becomes 8 bits, and P1\_0 (/D8) through P1\_7 (/D15) can be used as I/O ports (see Figure 3.1 for details).

When the voltage level input to the BYTE pin is low, the external data bus width becomes 16 bits, and P1\_0 (/D8) through P1\_7 (/D15) operate as a data bus (D8 through D15) (see Figure 3.1 for details).

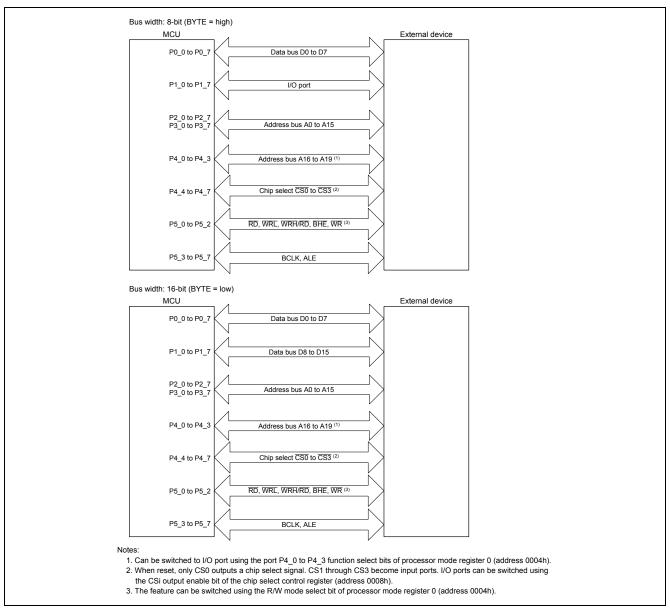
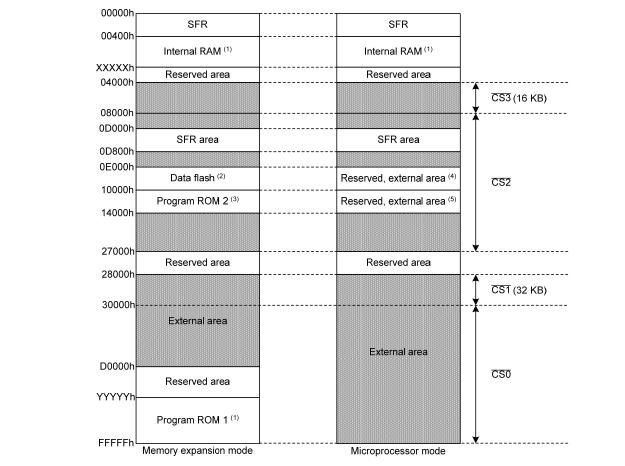


Figure 3.1 BYTE Pin Level and External Data Bus Width

# 3.2.2 Chip Select and Address Bus

Chip select signals (pins  $P4\_4/\overline{CS0}$  through  $P4\_7/\overline{CS3}$ ) are output in areas resulting from dividing a 1-MB memory space into four. This document does not explain the 4-MB memory space (refer to the hardware manual for details). To output a chip select signal, the chip select output must be enabled by setting the chip select control register. Figure 3.2 shows addresses where chip select signals become active low.

Since the internal area and external area in memory expansion mode are different from those in microprocessor mode, there is a difference between areas for which  $\overline{CSO}$  is output. When an internal ROM/RAM area is being accessed, no chip select signal is output, and the address bus does not change (the address of the external area that was accessed previously is held).



#### Notes:

1. When the PM13 bit in the PM1 register is 0, 15 KB of the internal RAM and 192 KB of the internal ROM can be used. See the table below for addresses XXXXXh and YYYYYh.

Inte	rnal RAM	Program ROM 1		
Capacity	Address XXXXXh	Capacity	Address YYYYYh	
12 KB	033FFh	128 KB	E0000h	
20 KB	20 KB 033FFh		D0000h	
31 KB	31 KB 033FFh		D0000h	
47 KB 033FFh		512 KB	D0000h	
		640 KB	D0000h	
		768 KB	D0000h	

- 2. When the PM10 bit is 0, this area is used as an external area; when the bit is 1, the area is used as internal ROM (data flash).
- 3. When the PRG2C0 bit in the PRG2C register is 1, this area is used as an external area; when the bit is 0, the area is used as internal ROM (program ROM 2).
- 4. When the PM10 bit is 0, this area is used as an external area; when the bit is 1, the area is used as a reserved area.
- 5. When the PRG2C0 bit in the PRG2C register is 1, this area is used as an external area; when the bit is 0, the area is used as a reserved area.

Figure 3.2 Addresses in which Chip Select Signals Become Active Low

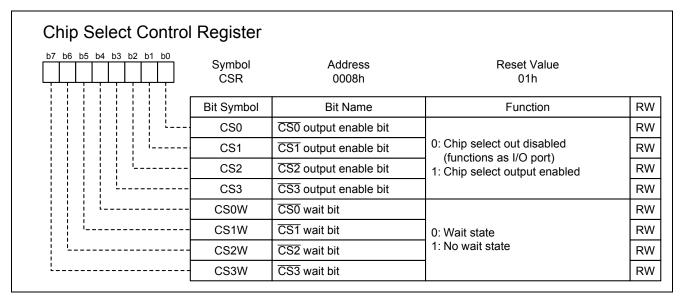


Figure 3.3 Chip Select Control Register

### 3.2.3 Bus Types

The M16C/65 Group has two types of buses: a separate bus where separate pins are used for address output and data I/O and a multiplexed bus where pins are time-multiplexed and switched between address output and data I/O to save the number of pins used.

A separate bus is used to access devices such as ROM and RAM which have separate buses. The areas accessed via separate buses can be allocated for programs and data.

A multiplexed bus is used to access devices such as ASSPs which have multiplexed buses. The areas accessed via a multiplexed bus can only be allocated for data. Programs cannot be located in these areas.

The areas accessed via a multiplexed bus can be selected from the  $\overline{CS2}$  area,  $\overline{CS1}$  area, or entire space by setting the multiplexed bus select bits (bits 4 and 5) in the processor mode register 0 (address 0004h). However, the entire space cannot be selected when operating in microprocessor mode.

Areas not accessed via a multiplexed bus are accessed through separate buses.

When accessing an area set for a multiplexed bus, the BYTE pin is high, data bus D0 to D7 are multiplexed with address bus A0 to A7.

When the BYTE pin is low, data bus D0 to D7 are multiplexed with address bus A1 to A8. In either case, the bus is switched between data and address.

In the latter case, however, the addresses of the connected devices are mapped into even addresses (every other address) of the M16C/65. Therefore, be sure to access the M16C/65's even addresses in bytes when accessing a connected device.

# 3.2.4 R/W Modes

The read/write signal that is output when accessing an external area can be selected between  $\overline{RD}$  /  $\overline{BHE}$  /  $\overline{WR}$  and the  $\overline{RD}$  /  $\overline{WRH}$  /  $\overline{WRL}$  modes by setting the R/W mode select bit (bit 2) in processor mode register 0 (address 0004h). Use the  $\overline{RD}$  /  $\overline{BHE}$  /  $\overline{WR}$  mode to access a 16-bit wide RAM and the  $\overline{RD}$  /  $\overline{WRH}$  /  $\overline{WRL}$  mode to access an 8-bit wide RAM.

When the M16C/65 is reset, the  $\overline{RD}$  /  $\overline{BHE}$  /  $\overline{WR}$  mode is selected by default. When changing modes, change the  $\overline{RD}$  /  $\overline{BHE}$  /  $\overline{WR}$  to the  $\overline{RD}$  /  $\overline{WRH}$  /  $\overline{WRL}$  mode before accessing external RAM.

Refer to the  $\overline{RD}$  /  $\overline{BHE}$  /  $\overline{WR}$  and  $\overline{RD}$  /  $\overline{WRH}$  /  $\overline{WRL}$  connection examples shown in section 3.3"Connection Examples".

# 3.3 Connection Examples

# 3.3.1 Connecting 16-bit Memory to a 16-bit Wide Data Bus Connecting 16-bit

Figure 3.4 shows an example of connecting HM6216514LTTI (SRAM). In this diagram, when reset, the MCU starts operating in single-chip mode. Change this mode to memory expansion mode in a program.

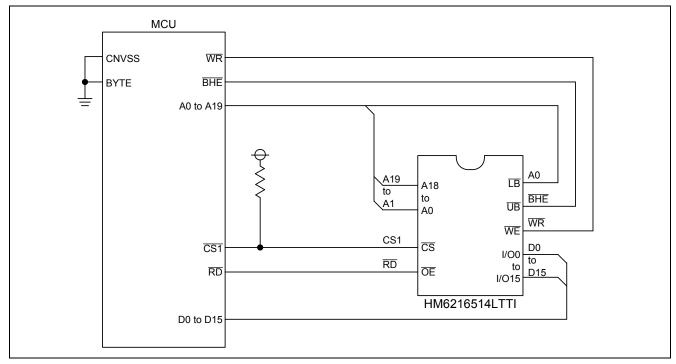


Figure 3.4 Connecting HM6216514LTTI to a 16-bit Wide Data Bus

# 3.3.2 Connecting 8-bit Memory to a 16-bit Wide Data Bus

Figure 3.5 shows an example of connecting two M5M5V108DVP's (SRAM) to a 16-bit data bus. In this diagram, when reset, the MCU starts operating in single-chip mode. Change this mode to memory expansion mode in a program.

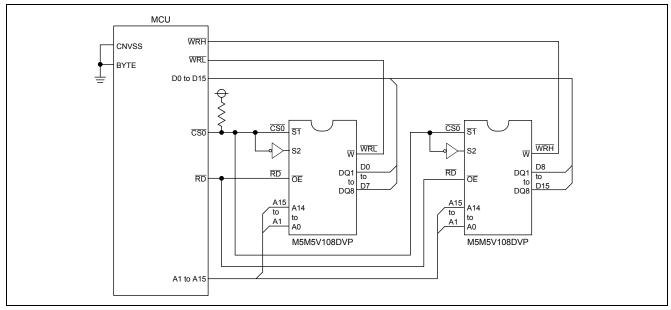


Figure 3.5 Connecting Two M5M5V108DVP's to a 16-bit Wide Data Bus

# 3.3.3 Connecting 8-bit Memory to an 8-bit Wide Data Bus

Figure 3.6 shows an example of connecting two M5M5V108DVP's (SRAM) to an 8-bit wide data bus. In this diagram, when reset, the MCU starts operating in single-chip mode. Change this mode to memory expansion mode in a program.

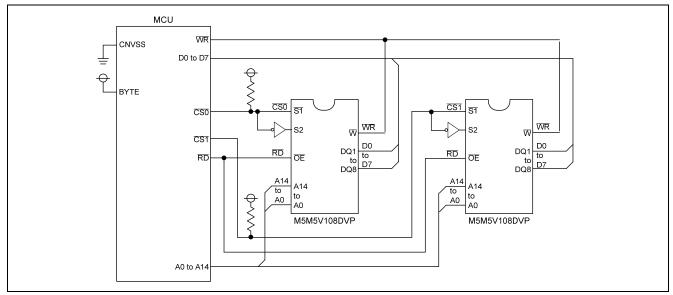


Figure 3.6 Connecting Two M5M5V108DVP's to an 8-bit Wide Data Bus

#### 3.4 Connectable Memories

### 3.4.1 Operation Frequency and Access Time

Connectable memories depend upon the BCLK frequency f(BCLK). The frequency of f(BCLK) is equal to that of BCLK, and is contingent on the oscillator frequency and on the system clock select bit settings (bit 6 of CM0 register, and bits 6 and 7 of CM1 register).

(1) Read cycle time (tCR)/write cycle time (tCW)

tCR and tCW must satisfy the following conditional expressions:

• With the wait option cleared

 $tCR < 10^9/f(BCLK)$  and  $tCW < 10^9/f(BCLK)$ 

• With the wait option selected

 $tCR < n \times 10^9 / f(BCLK)$  and  $tCW < (n+1) \times 10^9 / f(BCLK)$ 

Note: For details on the value of n, refer to Table 3.1.

(2) Address access time [ta(A)]

ta(A) must satisfy the following conditional expressions:

- (a) Vcc = 5 V
  - With the wait option cleared

$$ta(A) < 10^9/f(BCLK) - 65(ns)*$$

· With the wait option selected

$$ta(A) < n \times 10^9 / f(BCLK) - 65(ns)^*$$

\* 
$$65(ns) = td(BCLK - AD) + tsu(DB - RD) - th(BCLK - RD)$$

= (address output delay time) + (data input setup time) – (RD signal output hold time)

- (b) Vcc = 3 V
  - With the wait option cleared

$$ta(A) < 10^9/f(BCLK) - 80(ns)*$$

• With the wait option selected

$$ta(A) < n \times 10^9 / f(BCLK) - 80(ns)^*$$

\* 
$$80(ns) = td(BCLK-AD) + tsu(DB - RD) - th(BCLK - RD)$$

= (address output delay time) + (data input setup time) – (RD signal output hold time)

Note: For details on the value of n, refer to Table 3.1.

(3) Chip select access time [ta(S)]

ta(S) must satisfy the following conditional expressions:

- (a) Vcc = 5 V
  - With the wait option cleared

$$ta(S) < 10^9/f(BCLK) - 65(ns)^*$$

• With the wait option selected

$$ta(S) < n \times 10^9 / f(BCLK) - 65(ns)^*$$

\* 
$$65(ns) = td(BCLK - CS) + tsu(DB - RD) - th(BCLK - RD)$$

= (chip select output delay time) + (data input setup time) - (RD signal output hold time)

- (b) Vcc = 3 V
  - With the wait option cleared

$$ta(S) < 10^9/f(BCLK) - 80(ns)*$$

• With the wait option selected

$$ta(S) < n \times 10^9 / f(BCLK) - 80(ns)^*$$

\* 
$$80(ns) = td(BCLK - CS) + tsu(DB - RD) - th(BCLK - RD)$$

= (chip select output delay time) + (data input setup time) – (RD signal output hold time)

Note: For details on the value of n. refer to Table 3.1.

(4) Output enable time [ta(OE)]

ta(OE) must satisfy the following conditional expressions:

- (a) Vcc = 5 V
  - When no waits are inserted

$$ta(OE) < 0.5 \times 10^{9} / f(BCLK) - 45(ns) = tac1(RD-DB)$$

• When one to three waits are inserted

$$ta(OE) < (n + 0.5) \times 10^9 / f(BCLK) - 45(ns) = tac2(RD-DB)$$

Note: n is 1 when inserting one wait, 2 when inserting two waits, and 3 when inserting three waits.

• When accessing a multiplexed bus area

$$ta(OE) < (n - 0.5) \times 10^9 / f(BCLK) - 45(ns) = tac3(RD-DB)$$

Note: n is 2 when inserting two waits, and 3 when inserting three waits.

• When setting  $2\phi + 3\phi$  or more

$$ta(OE) < n \times 10^9 / f(BCLK) - 45(ns) = tac4(RD-DB)$$

Note: n is 3 for  $2\varphi + 3\varphi$ , 4 for  $2\varphi + 4\varphi$ , 4 for  $3\varphi + 4\varphi$ , and 5 for  $4\varphi + 5\varphi$ .

- (b) Vcc = 3 V
  - · When no waits are inserted

$$ta(OE) < 0.5 \times 10^{9} / f(BCLK) - 60(ns) = tac1(RD-DB)$$

· When one to three waits are inserted

$$ta(OE) < (n + 0.5) \times 10^9 / f(BCLK) - 60(ns) = tac2(RD-DB)$$

Note: n is 1 when inserting one wait, 2 when inserting two waits, and 3 when inserting three waits.

· When accessing a multiplexed bus area

$$ta(OE) < (n - 0.5) \times 10^9 / f(BCLK) - 60(ns) = tac3(RD-DB)$$

Note: n is 2 when inserting two waits, and 3 when inserting three waits.

• When setting  $2\phi + 3\phi$  or more

$$ta(OE) < n \times 10^9 / f(BCLK) - 60(ns) = tac4(RD-DB)$$

Note: n is 3 for  $2\phi + 3\phi$ , 4 for  $2\phi + 4\phi$ , 4 for  $3\phi + 4\phi$ , and 5 for  $4\phi + 5\phi$ .

- (5) Data setup time [tsu(D)]
  - tsu(D) must satisfy the following conditional expressions:
  - (a) Vcc = 5 V
    - With the wait option cleared

$$tsu(D) < 10^9/(f(BCLK)\times 2) - 40(ns)*$$

• With the wait option selected

$$tsu(D) < (n+1) \times 10^9 / (f(BCLK) \times 2) - 40(ns)^*$$

\* 
$$40(ns) = td(BCLK - DB) - th(BCLK - WR)$$

= (data output delay time) – (WR signal output hold time)

- (b) Vcc = 3 V
  - With the wait option cleared

$$tsu(D) < 10^9/(f(BCLK) \times 2) - 40(ns)*$$

• With the wait option selected

$$tsu(D) < (n+1) \times 10^9 / (f(BCLK) \times 2) - 40(ns)^*$$

\* 
$$40(ns) = td(BCLK - DB) - th(BCLK - WR)$$

= (data output delay time) – (WR signal output hold time)

Note: n is 1 when inserting one wait, 2 when inserting two waits, and 3 when inserting three waits.

See Figure 3.7 and Figure 3.8 for details. In the figures below, "M." means "When Accessing with a Multiplexed Bus".

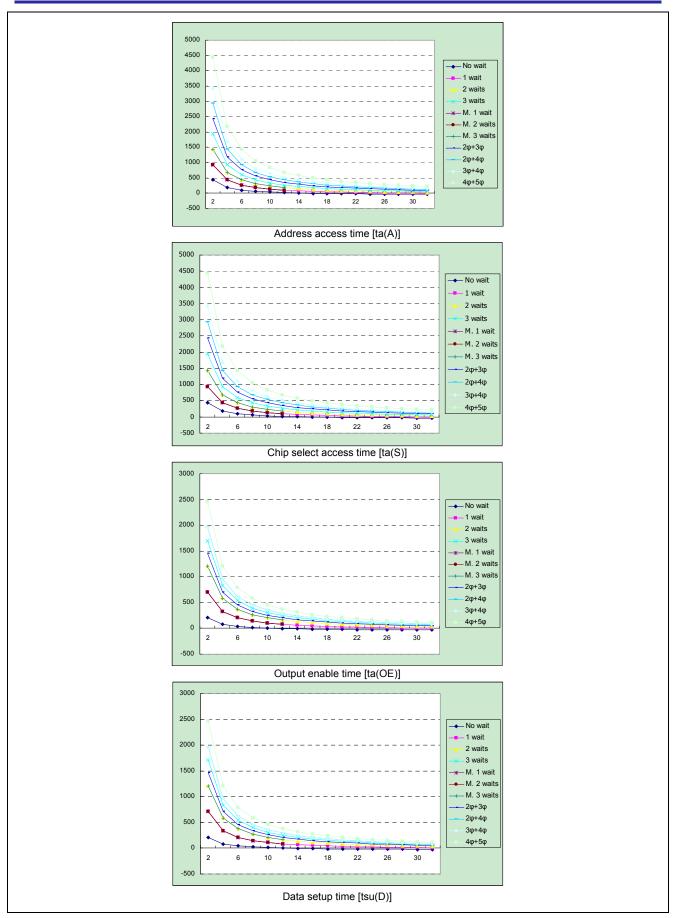


Figure 3.7 Relation between the BCLK Frequency and Memory When Vcc = 5 V

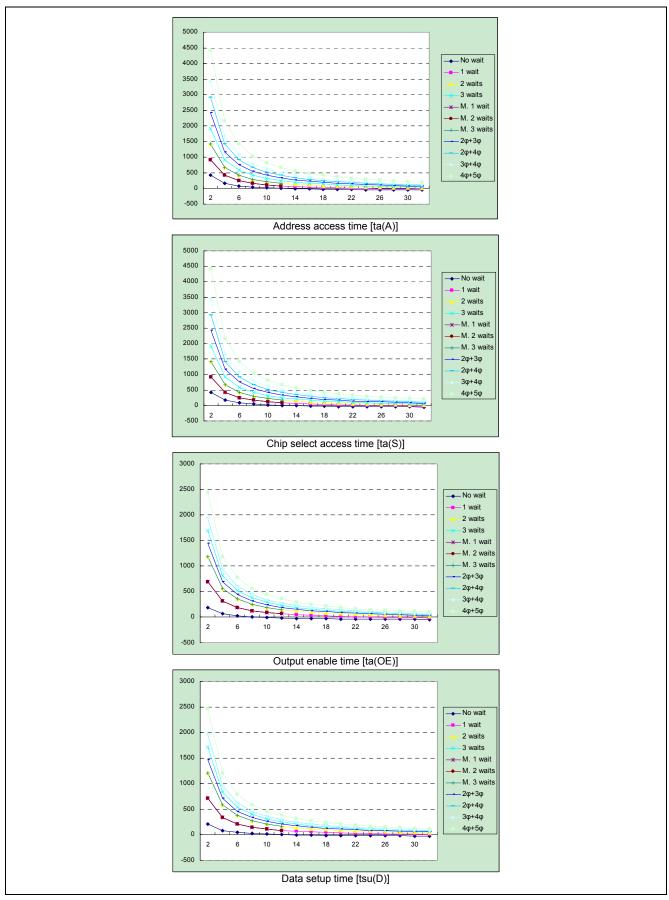


Figure 3.8 Relation between the BCLK Frequency and Memory When Vcc = 3 V

# 3.4.2 Connecting Low-Speed Memory

To connect memory with long address access time [ta(A)], either decrease the frequency of BCLK or insert a software wait. Use the  $\overline{RDY}$  feature to connect memory having the timing that precludes connection though a software wait is inserted

#### (1) Using software wait

The PM17 bit in the PM1 register, which is a software-wait-related bit, affects both the internal memory and the external area.

Software waits can be inserted to an external area by setting the PM17 bit in the PM1 register, setting the CSiW bit in the CSR register, and bits CSEi1W to CSEi0W in the CSE register for each  $\overline{CSi}$  (i = 0 to 3). To use the  $\overline{RDY}$  signal, set the corresponding CSiW bit to 0 (wait state). See Table 3.1 "Bits and Bus Cycles Related to Software Wait States (External Area)" for details.

Table 3.1 Bits and Bus Cycles Related to Software Wait States (External Area)

	Bus Mode	Setting of Software-Wait-Related Bits				Software	
Area		PM17	CSiW	CSEi1W to CSEi0W	EWCi1 to EWCi0	Wait Cycles	Bus Cycles
		0	1	00b	_	None	1 BCLK cycle (read)
		0	'	005	_	None	2 BCLK cycles (write)
		-	0	00b	-	1 (1φ + 1φ)	2 BCLK cycles (4)
		-	0	01b	-	2 (1φ + 2φ)	3 BCLK cycles
	Separate bus	-	0	10b	-	3 (1φ + 3φ)	4 BCLK cycles
area		- 0	11b	00b	$(2\phi + 3\phi)$	5 BCLK cycles	
				01b	$(2\phi + 4\phi)$	6 BCLK cycles	
l ä			0	110	10b	$(3\phi + 4\phi)$	7 BCLK cycles
External					11b	$(4\phi + 5\phi)$	9 BCLK cycles
"		1	0 (3)	00b	-	1 (1φ + 1φ)	2 BCLK cycles
		-	0 (2)	00b	-	1 <sup>(5)</sup>	3 BCLK cycles
	Multiplexed	-	0 (2)	01b	-	2	3 BCLK cycles
	bus	-	0 (2)	10b	·	3	4 BCLK cycles
		1	0 (2, 3)	00b	-	1 (5)	3 BCLK cycles

i = 0 to 3

PM17: Bit in the PM1 register CSiW: Bits in the CSR register (1)

CSEi1W and CSEi0W: Bits in the CSE register EWCi1 and EWCi0: Bits in the EWC register

#### Notes:

- 1. To use the RDY signal, set the CSiW bit to 0 (wait state).
- 2. When accessing with a multiplexed bus, set the CSiW bit to 0 (wait state).
- 3. To access an external area when the PM17 bit is 1, set the CSiW bit to 0 (wait state).
- 4. After reset, the PM17 bit is set to 0 (no wait state), bits CS0W to CS3W are set to 0 (wait state), and the CSE register is set to 00h (one wait state for  $\overline{\text{CS0}}$  to  $\overline{\text{CS3}}$ ). Therefore, all external areas are accessed with one wait state.
- 5. When setting one wait in the multiplexed bus, the bus cycle is the same as two waits.
- (2)  $\overline{RDY}$  function usage

<sup>-</sup> indicates that either 0 or 1 can be set.

To use the RDY function, insert a software wait.

The  $\overline{RDY}$  function operates when the BCLK signal falls while the  $\overline{RDY}$  pin is low; the bus does not vary for one BCLK cycle, and the state at that moment is held.

The  $\overline{RDY}$  function holds the state of bus for the period in which the  $\overline{RDY}$  pin is low, and releases it when the BCLK signal falls while the  $\overline{RDY}$  pin is high. Figure 3.9 shows an example of the  $\overline{RDY}$  circuit f(XIN)=10 MHz that holds the state of bus for one BCLK cycle.

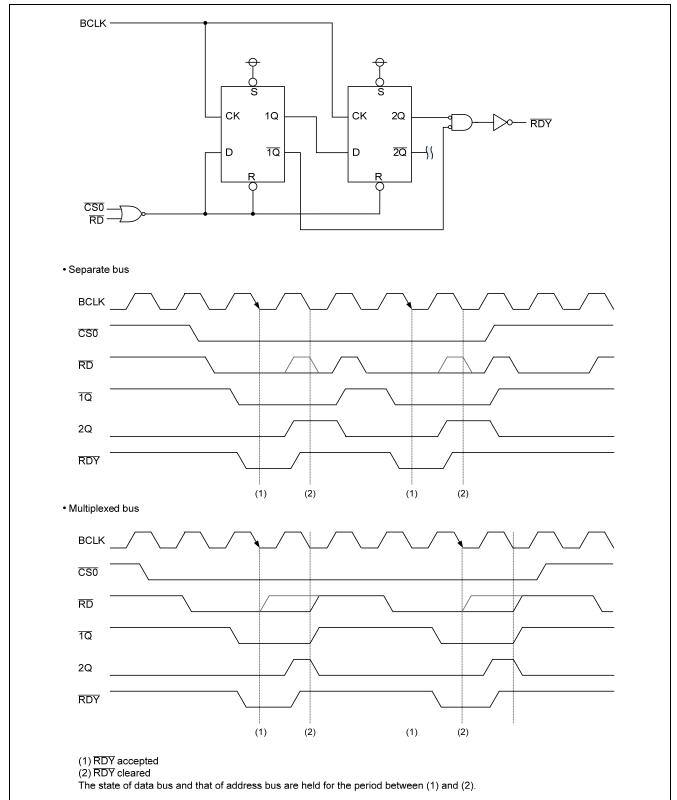


Figure 3.9 RDY Circuit Holding State of Bus for One BCLK f(XIN) = 10 MHz

# 3.4.3 Connectable Memories

Connectable memories and their maximum frequencies are below.

The maximum frequency for the M16C/65 Group is 32 MHz when Vcc = 2.7 to 5.5 V.

In the tables below, "M." means "When Accessing with a Multiplexed Bus".

#### (1) 5 V

#### (a) When no waits are inserted

Maximum Frequency (MHz)	Model No.
6	HM6216514LTTI-5SL

#### (b) When one to three waits are inserted

Ma	ximum Frequency (M	Model No.	
1 wait	2 waits	Widdel No.	
16	25	<b>—</b> <sup>(1)</sup>	HM6216514LTTI-5SL

# (c) When accessing a multiplexed bus area

Ma	ximum Frequency (M	Model No.	
M. 1 wait M. 2 waits M. 3 waits			model No.
12.5	12.5	12.5	HM6216514LTTI-5SL

# (d) When setting $2\phi + 3\phi$ or more

	Maximum fre	quency (MHz)	Model No.	
2φ + 3φ	$2\phi + 3\phi$ $2\phi + 4\phi$ $3\phi + 4\phi$ $4\phi + 5\phi$			Widdel No.
_ (1)	- <sup>(1)</sup>	_ (1)	- <sup>(1)</sup>	HM6216514LTTI-5SL

#### (2) 3 V

#### (a) When no waits are inserted

Maximum Frequency (MHz)	Model No.
5	M5M5V108DVP-70HI

#### (b) When one to three waits are inserted

Ma	ximum Frequency (M	Model No.	
1 wait	2 waits	Model No.	
13	20	26	M5M5V108DVP-70HI

#### (c) When accessing a multiplexed bus area

Max	ximum Frequency (M	Model No.	
M. 1 wait	M. 2 waits	M. 3 waits	Woder No.
12.5	12.5	12.5	M5M5V108DVP-70HI

### (d) When setting $2\phi + 3\phi$ or more

	Maximum Fre	quency (MHz)	Model No.	
2φ + 3φ	2φ + 4φ	3φ + 4φ	4φ + 5φ	Model No.
31	_ <sup>(1)</sup>	<b>–</b> <sup>(1)</sup>	- <sup>(1)</sup>	M5M5V108DVP-70HI

#### Note:

1. "-" means no limitation, the maximum frequency for the M16C/65 Group is 32 MHz.

Website and Support

Renesas Electronics Website

http://www.renesas.com/

Inquiries

http://www.renesas.com/inquiry

# **Revision History**

		Description	
Rev.	Date	Page	Summary
1.00	May 20, 2010	_	First edition issued

All trademarks and registered trademarks are the property of their respective owners.

# General Precautions in the Handling of MPU/MCU Products

The following usage notes are applicable to all MPU/MCU products from Renesas. For detailed usage notes on the products covered by this manual, refer to the relevant sections of the manual. If the descriptions under General Precautions in the Handling of MPU/MCU Products and in the body of the manual differ from each other, the description in the body of the manual takes precedence.

# 1. Handling of Unused Pins

- Handle unused pins in accord with the directions given under Handling of Unused Pins in the manual.
- The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible. Unused pins should be handled as described under Handling of Unused Pins in the manual.

#### 2. Processing at Power-on

- The state of the product is undefined at the moment when power is supplied.
- The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the moment when power is supplied.
  - In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the moment when power is supplied until the reset process is completed.
  - In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the moment when power is supplied until the power reaches the level at which resetting has been specified.

#### 3. Prohibition of Access to Reserved Addresses

- Access to reserved addresses is prohibited.
- The reserved addresses are provided for the possible future expansion of functions. Do not access these addresses; the correct operation of LSI is not guaranteed if they are accessed.

#### 4. Clock Signals

- After applying a reset, only release the reset line after the operating clock signal has become stable. When switching the clock signal during program execution, wait until the target clock signal has stabilized.
- When the clock signal is generated with an external resonator (or from an external oscillator) during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Moreover, when switching to a clock signal produced with an external resonator (or by an external oscillator) while program execution is in progress, wait until the target clock signal is stable.

#### 5. Differences between Products

- Before changing from one product to another, i.e. to one with a different type number, confirm that the change will not lead to problems.
- The characteristics of MPU/MCU in the same group but having different type numbers may differ because of the differences in internal memory capacity and layout pattern. When changing to products of different type numbers, implement a system-evaluation test for each of the products.

#### Notice

- 1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website
- 2. Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or
- 3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
- 4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
- 6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 7. Renesas Electronics products are classified according to the following three quality grades: "Standard", "High Quality", and "Specific". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as "Specific" without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is "Standard" unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc.
  - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools, personal electronic equipment; and industrial robots
  - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically
  - Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life
- 8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics.
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.



#### SALES OFFICES

Renesas Electronics Corporation

http://www.renesas.com

Refer to "http://www.renesas.com/" for the latest and detailed information

Renesas Electronics America Inc. 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220 1 Nicholson Road, Newmarket, Ontario L3 +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, German Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
7F, No. 363 Fu Shing North Road Taipei, Taiwan, R.O.C.
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 1 harbourFront Avenue, #06-10, keppel Bay Tower, Singapore 098632 Tel: +65-6213-0200, Fax: +65-6278-8001

Renesas Electronics Malaysia Sdn.Bhd.

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd. 11F., Samik Lavied or Bidg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea Tel: +82-2-558-3737, Fax: +82-2-558-5141

© 2010 Renesas Electronics Corporation, All rights reserved